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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Alan Bennett et al.  
Title: Non-Volatile Memory And Method With Block Management System  
Application No.: 10/750,155 Filing Date: December 30, 2003  
Examiner: Unknown Group Art Unit: 2818  
Docket No.: SNDK.343US0 Conf. No.: 7902

Certificate of Mailing Under 37 CFR 1.8

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on June 14, 2004

Signature *Tracy Mignone*

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**INFORMATION DISCLOSURE STATEMENT**

Dear Sir:

Pursuant to 37 C.F.R. §§ 1.56, 1.97 and 1.98, Applicant(s) call(s) the documents listed on the enclosed Form PTO-1449 to the Examiner's attention in this patent application.

This application has a filing date after June 30, 2003. Copies of the U.S. Patent(s) and U.S. Published Patent Application(s) documents listed on the accompanying Form PTO-1449 are not enclosed.

Citation of these documents shall not be construed as (1) an admission that the documents are prior art with respect to the invention or inventions claimed in this application, (2) a representation that a search has been made (other than as indicated by any cited

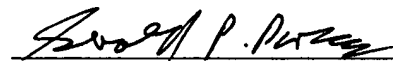
Attorney Docket No.:  
SNDK.343US0

Application No.:  
10/750,155

document), or (3) an admission that the cited information is, or is considered to be, material to patentability as defined in § 1.56(b).

This information disclosure statement is submitted under 37 C.F.R. § 1.97(b) and consequently no fee should be required. The Commissioner is authorized, however, to charge any fee that may be required, or to credit any overpayment, against Deposit Account No. 502664. This form is being submitted in duplicate.

Respectfully submitted,



Gerald P. Parsons  
Reg. No. 24,486

June 14, 2004

Date

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U.S. Department of Commerce, Patent and Trademark				Atty. Docket No.		Application No.	
INFORMATION DISCLOSURE STATEMENT BY APPLICANT				SNDK.343US0		10/750,155	
				Applicant(s)		Conf. No.	
(Use several sheets if necessary)				Alan Bennett et al.		7902	
				Filing Date		Group	
				December 30, 2003		2818	

U.S. Patent Documents							
Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate
	1	5,070,032	12/3/91	Yuan et al.			
	2	5,095,344	3/10/92	Harari			
	3	5,313,421	5/17/94	Guterman et al.			
	4	5,315,541	5/24/94	Harari et al.			
	5	5,343,063	8/30/94	Yuan et al.			
	6	5,570,315	10/29/96	Tanaka et al.			
	7	5,661,053	8/26/97	Yuan			
	8	5,768,192	6/16/98	Eitan			
	9	5,903,495	5/11/99	Takeuchi et al.			
	10	6,011,725	1/4/00	Eitan			
	11	6,046,935	4/4/00	Takeuchi et al.			
	12	6,222,762	4/24/01	Guterman et al.			
	13	6,567,307	5/20/03	Estakhri			

U.S. Published Patent Application Documents							
*Examiner Initial		Document Number	Date	Name	Class	Subclass	Filing Date If Appropriate

Foreign Patent Documents								
							Translation	
		Document	Date	Country	Class	Subclass	Yes	No
	14	WO 00/049488	8/24/2000	WIPO				
	15	WO 03/027828	4/3/2003	WIPO				

OTHER ART (Including Author, Title, Date, Pertinent Pages, Etc.)		
	16	Eitan et al., "NROM: A Novel Localized Trapping, 2-Bit Nonvolatile Memory Cell," IEE Electron Device Letters, vol. 21, no. 1, November 2000, pp. 543-545.

Examiner	Date Considered
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\*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with your communication to applicant.